MSKSEMI















ESD

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Broduct data sheet











1. BASE

2. EMITTER

SOT - 23 3. COLLECTOR TRANSISTOR (NPN)

FEATURES

Complementary to S9015-MS

MARKING: J6

MAXIMUM RATINGS (T_a=25°C unless otherwise noted)

Symbol	Parameter	Value	Unit
V _{CBO}	Collector-Base Voltage	50	V
V _{CEO}	Collector-Emitter Voltage	45	V
V _{EBO}	Emitter-Base Voltage	5	V
lc	Collector Current	100	mA
Pc	Collector Power Dissipation	200	mW
R _{OJA}	Thermal Resistance From Junction To Ambient	625	°CW
T _J ,T _{stg}	Operation Junction and Storage Temperature Range	-55~+150	°C

ELECTRICAL CHARACTERISTICS (Ta=25℃ unless otherwise specified)

•		•	•			
Parameter	Symbol	Test conditions	Min	Тур	Max	Unit
Collector-base breakdown voltage	V _{(BR)CBO}	I _C = 100μΑ, I _E =0	50			V
Collector-emitter breakdown voltage	V _{(BR)CEO}	I _C = 0.1mA, I _B =0	45			V
Emitter-base breakdown voltage	V _{(BR)EBO}	I _E =100μΑ, I _C =0	5			V
Collector cut-off current	I _{CBO}	V _{CB} =50 V , I _E =0			0.1	μА
Collector cut-off current	I _{CEO}	V _{CE} =35V , I _B =0			1	μА
Emitter cut-off current	I _{EBO}	V _{EB} = 3V , I _C =0			0.1	μА
DC current gain	h _{FE}	V _{CE} =5V, I _C = 1mA	200		1000	
Collector-emitter saturation voltage	V _{CE} (sat)	I _C =100 mA, I _B = 5mA			0.3	V
Base-emitter saturation voltage	V _{BE} (sat)	I _C =100 mA, I _B = 5mA			1	V
Transition frequency	f _T	V _{CE} =5V, I _C = 10mA f=30MHz	150			MHz

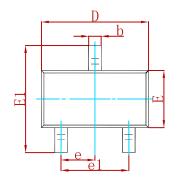
CLASSIFICATION OF hFE

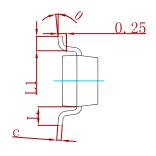
Rank	L	Н
Range	200-450	450-1000

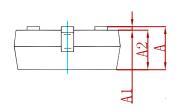




PACKAGE MECHANICAL DATA

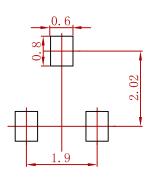






Cumbal	Dimensions	In Millimeters	Dimensions In Inches		
Symbol	Min	Max	Min	Max	
Α	0.900	1.150	0.035	0.045	
A1	0.000	0.100	0.000	0.004	
A2	0.900	1.050	0.035	0.041	
b	0.300	0.500	0.012	0.020	
С	0.080	0.150	0.003	0.006	
D	2.800	3.000	0.110	0.118	
E	1.200	1.400	0.047	0.055	
E1	2.250	2.550	0.089	0.100	
е	0.950 TYP		0.037	7 TYP	
e1	1.800	2.000	0.071	0.079	
L	0.550 REF		0.022 REF		
L1	0.300	0.500	0.012	0.020	
θ	0°	8°	0°	8°	

Suggested Pad Layout



- 1.Controlling dimension:in millimeters.2.General tolerance:± 0.05mm.3.The pad layout is for reference purposes only.

REEL SPECIFICATION

P/N	PKG	QTY
S9014-MS	SOT-23	3000



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